



GaAs MMIC I/Q Mixer 8 - 12 GHz

Typical Applications

The HMC1056LP4BE is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

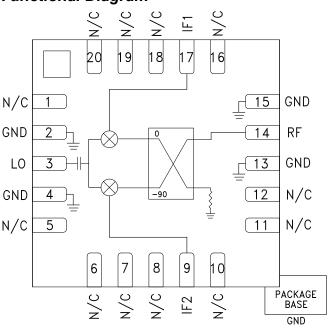
Features

Wide IF Bandwidth: DC - 4 GHz

Image Rejection: 25 dBc LO to RF isolation: 40 dB High Input IP3: 18 dBm

20 Lead 4x4 mm SMT Package: 16 mm²

Functional Diagram



General Description

The HMC1056LP4BE is a compact I/Q MMIC mixer in a leadless "Pb free" SMT package, which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs Schottky diode process. A low frequency quadrature hybrid was used to produce a 100MHz LSB IF output. This product is a much smaller alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC1056LP4BE eliminates the need for wire bonding and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25$ °C, IF = 100 MHz, LSB, LO = +10 dBm [1]

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF/LO		8 - 10			10 - 12		GHz
Frequency Range, IF		DC - 4			DC - 4		GHz
Conversion Loss		8	11		8	11	dB
Image Rejection	18	25		12	18		dBc
LO to RF isolation	33	40		33	40		dB
LO to IF isolation		35			40		dB
IP3 (input)		18			17		dBm
Amplitude Balance [2]		+0.5			+1.5		dB
Phase Balance ^[2]		+2.5			-2.5		Deg

^[1] Unless otherwise noted all measurements performed as downconverter.

^[2] Data taken without external 90° hybrid.

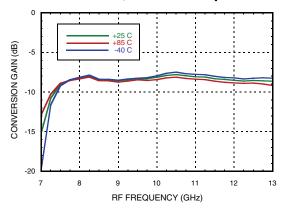




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

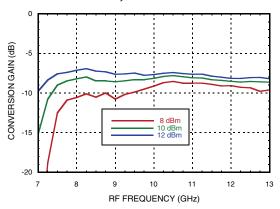


Image Rejection, LSB vs. Temperature

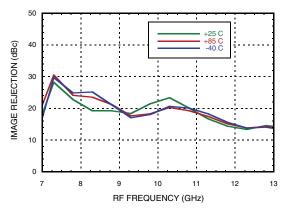
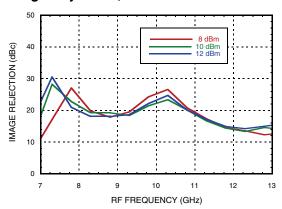
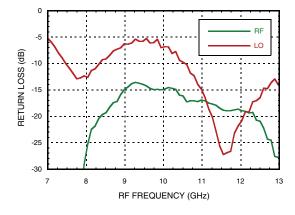


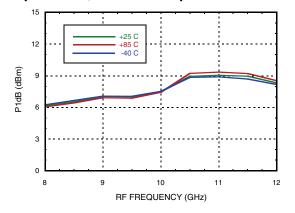
Image Rejection, LSB vs. LO Drive



Return Loss



Input P1dB, LSB vs. Temperature

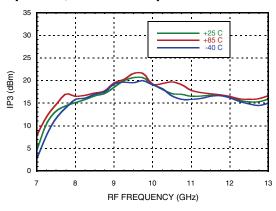


[1] Data taken without external IF 90° hybrid

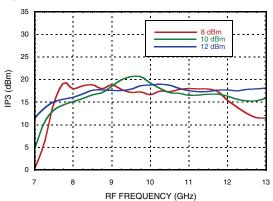


Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

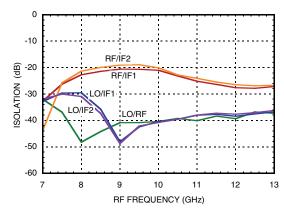
Input IP3, LSB vs. Temperature



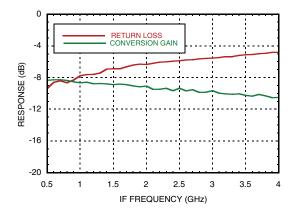
Input IP3, LSB vs. LO Drive



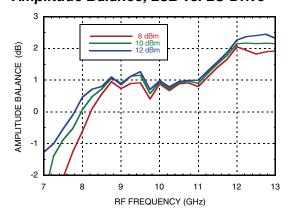
Isolations



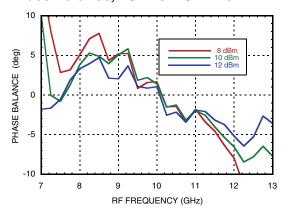
IF Bandwidth*



Amplitude Balance, LSB vs. LO Drive



Phase Balance, LSB vs. LO Drive



^{*} Conversion gain data taken with external IF hybrid.

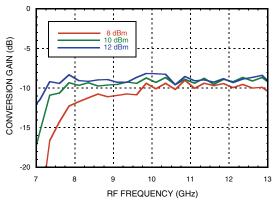




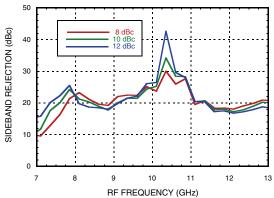
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

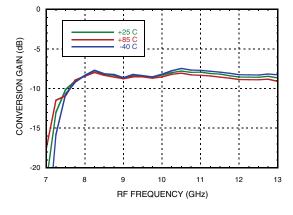
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

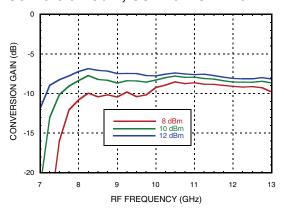


Image Rejection, USB vs. Temperature

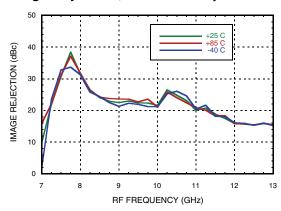
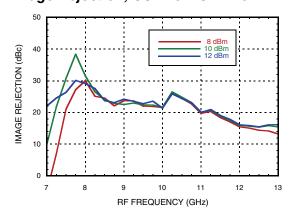


Image Rejection, USB vs. LO Drive

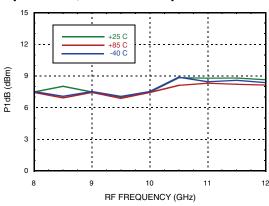




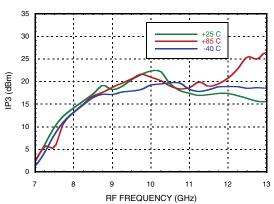
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

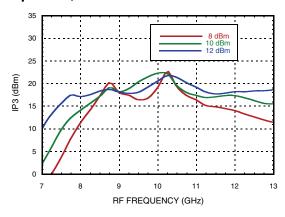
Input P1dB, USB vs. Temperature



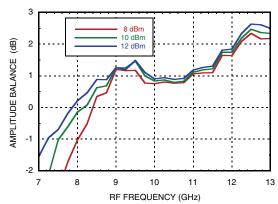
Input IP3, USB vs. Temperature



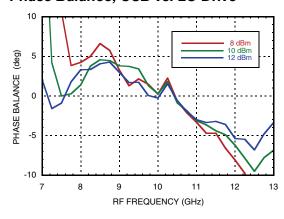
Input IP3, USB vs. LO Drive



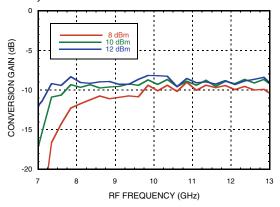
Amplitude Balance, USB vs. LO Drive



Phase Balance, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



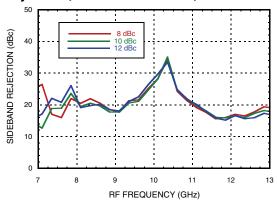




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 100 MHz

Upconverter Performance, Sideband Rejection, USB vs. LO Drive,



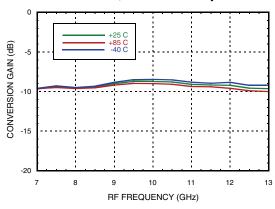




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

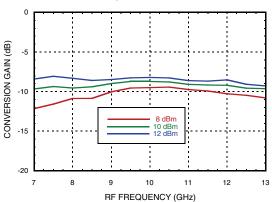


Image Rejection, LSB vs. Temperature

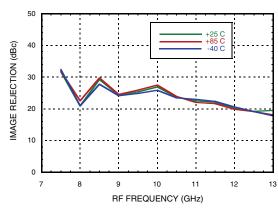
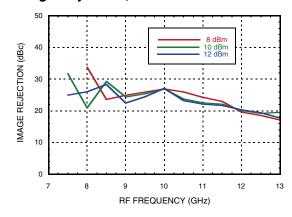
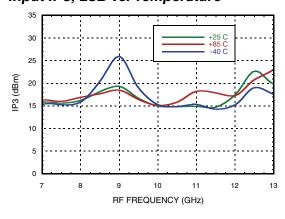


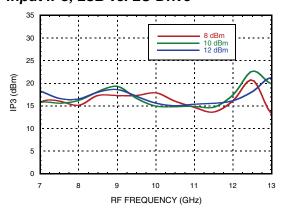
Image Rejection, LSB vs. LO Drive



Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive

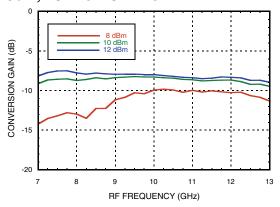




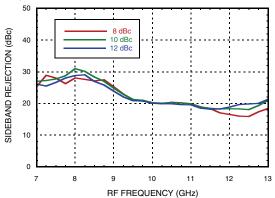
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

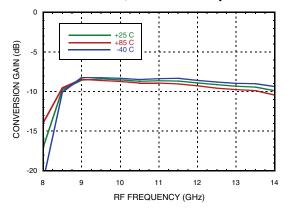
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

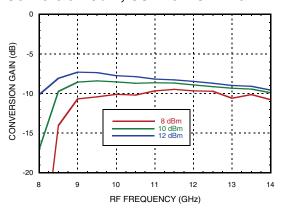


Image Rejection, USB vs. Temperature

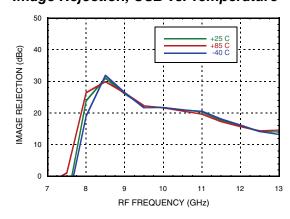
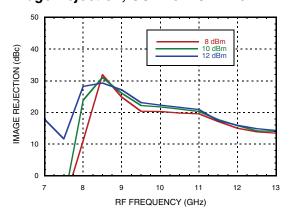


Image Rejection, USB vs. LO Drive



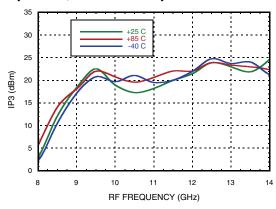




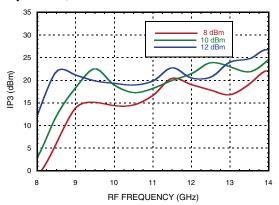
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

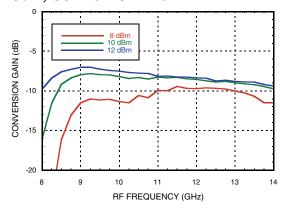
Input IP3, USB vs. Temperature



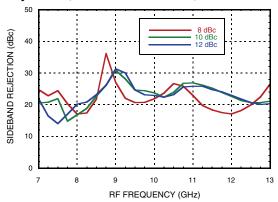
Input IP3, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



Upconverter Performance, Sideband Rejection, USB vs. LO Drive,

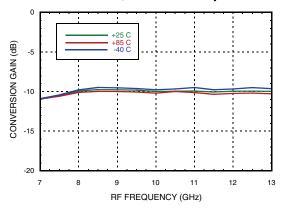




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

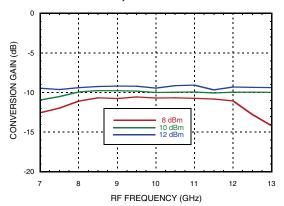


Image Rejection, LSB vs. Temperature

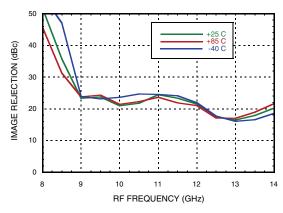
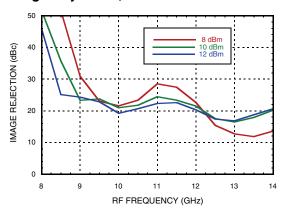
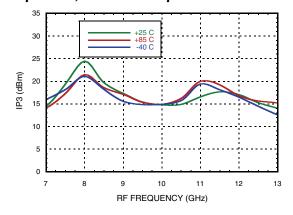


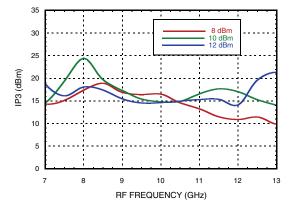
Image Rejection, LSB vs. LO Drive



Input IP3, LSB vs. Temperature

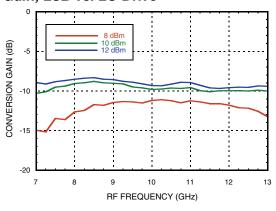


Input IP3, LSB vs. LO Drive

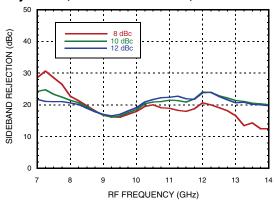


Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

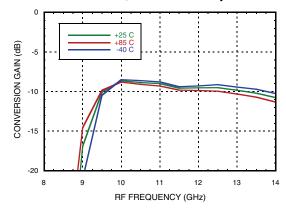
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

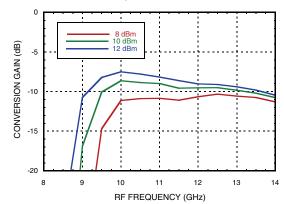


Image Rejection, USB vs. Temperature

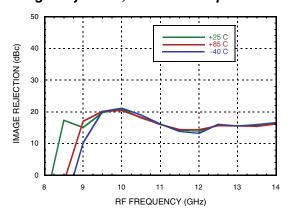
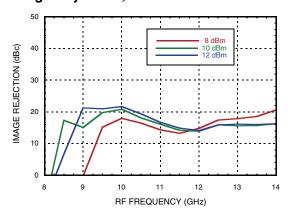


Image Rejection, USB vs. LO Drive

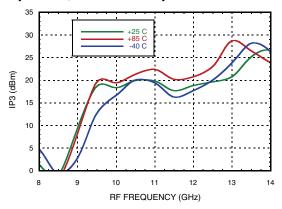




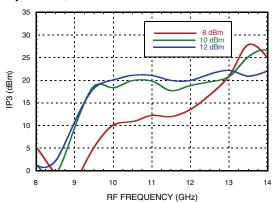


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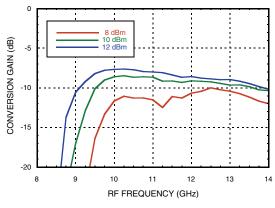
Input IP3, USB vs. Temperature



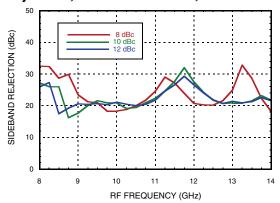
Input IP3, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



Upconverter Performance, Sideband Rejection, USB vs. LO Drive,



Harmonics of LO

LO From (CUT)	nLO Spur at RF Port					
LO Freq. (GHz)	1	2	3	4		
7	41.3	37.6	74.4	74.2		
8	36.3	36.3	52	82.1		
9	37.2	52.9	63.6	81.4		
10	36.8	56.4	65.5	100.4		
11	37.3	59.8	68.9	68.8		
12	37.4	56.2	65.3	78.9		
13	38.1	56.4	69.6	х		

LO = + 10 dBm

Values in dBc below LO level measured at RF Port.

MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	xx	8	38	48	60
1	8	0	28	43	60
2	64	50	56	48	67
3	94	78	67	64	78
4	х	х	х	х	х

RF = 10 GHz @ -10 dBm

LO = 10.1 GHz @ +10 dBm

Data taken without IF hybrid

All values in dBc below IF power level





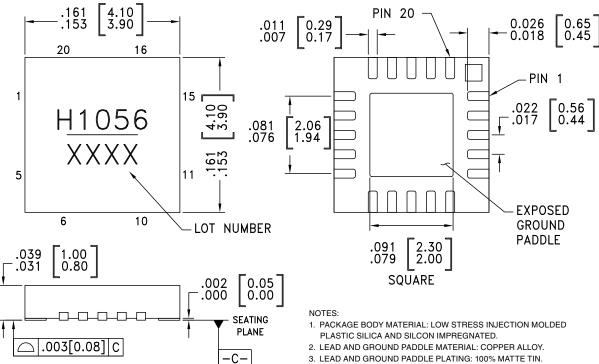
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Absolute Maximum Ratings

IF Input (At LO = 10 dBm and RF = -10 dBm)	+15.5 dBm	
RF Input (At 10 dBm LO power)	+16 dBm	
LO Input (At -10 dBm RF power)	+17 dBm	
Channel Temperature	175 °C	
Continuous Pdiss (T = 85°C) (derate 8.9 mW/°C above 85°C)	800 mW	
Thermal Resistance (channel to ground paddle)	112 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD Sensitivity (HBM)	Class 0, Passed 150V	



Outline Drawing



- 3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 6. PAD BURR LENGTH SHALL BE 0.15mm MAX. PAD BURR HEIGHT SHALL BE 0.05mm MAX.
- 7. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB BE GROUND

Package Information

I	Part Number	Package Body Material	Lead Finish	MSL Rating [2]	Package Marking [1]
	HMC1056LP4BE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	<u>H1056</u> XXXX

^{[1] 4-}Digit lot number XXXX

^[2] Max peak reflow temperature of 260 °C





GaAs MMIC I/Q Mixer 8 - 12 GHz

Pin Descriptions

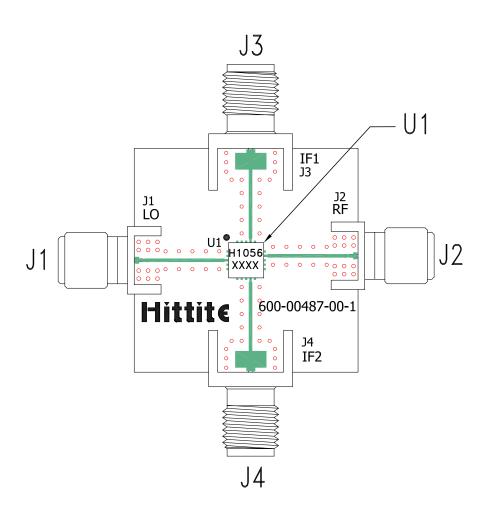
Pin Number	Function	Description	Interface Schematic
1, 5-8, 10-12, 16, 18-20	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2, 4, 13, 15	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	○ GND =
3	LO	This pin is AC coupled and matched to 50 Ohms .	L0 ○────
9	IF2	Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should	IF1,IF2 O
17	IF1	be used. For operation to DC this pin must not source/sink more than 3mA of current or part non function and possible part failure will result.	
14	RF	This pin is matched to 50 Ohms.	RF ○──





GaAs MMIC I/Q Mixer 8 - 12 GHz

Evaluation PCB



List of Materials for Evaluation PCB EVAL01-HMC1056LP4B[1]

Item	Description	
J1, J2	PCB Mount SMA RF Connector, SRI	
J3 - J4	PCB Mount SMA Connector, Johnson	
U1	HMC1056LP4BE	
PCB [2]	600-00487-00-1 Evaluation Board	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350



MIXERS - I/Q MIXERS, IRMS & RECEIVERS - SMT

ANALOGDEVICES



Notes:

GaAs MMIC I/Q Mixer 8 - 12 GHz

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Analog Devices Inc.:

EVAL01-HMC1056LP4B HMC1056LP4BETR